INTEGRATED CIRCUITS

DATA SHEET

74ALVC16245/74ALVCH16245

2.5V/3.3V 16-bit bus transceiver with direction pin (3-State)

Product specification Supersedes data of 1998 Jun 16 IC24 Data Handbook





16-bit bus transceiver with direction pin (3-State)

74ALVC16245/ 74ALVCH16245

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTETM flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- All data inputs have bus hold (74ALVCH16245 only)
- Output drive capability 50Ω transmission lines @ 85°C
- Current drive ±24 mA at 3.0 V

DESCRIPTION

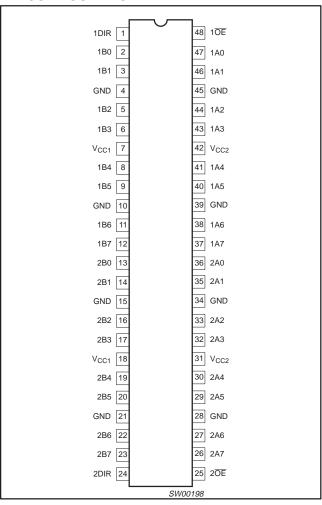
The 74ALVC16245(74ALVCH16245) is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions.

The 74ALVC16245(74ALVCH16245) features two output enable (nOE) inputs for easy cascading and two send/receive (nDIR) inputs for direction control. nOE controls the outputs so that the buses are effectively isolated. This device can be used as two 8-bit transceivers or one 16-bit transceiver.

The 74ALVCH16245 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

The 74ALVC16245 has 5V tolerant inputs.

PIN CONFIGURATION



QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	TYPICAL	UNIT			
t _{PHL} /t _{PLH}	Propagation delay An to Bn; Bn to An	V _{CC} = 2.5V, CL = 30pF V _{CC} = 3.3V, CL = 50pF		1.9	ns	
C _I	Input capacitance					
C _{I/O}	Input/output capacitance			8.0	pF	
C	Power dissipation capacitance per buffer	$V_1 = GND \text{ to } V_{CC}^{-1}$	Outputs enabled	29	pF	
C _{PD}	Fower dissipation capacitance per buller	Al = GIAD to ACC.	Outputs disabled	5	PΓ	

NOTE:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $\begin{aligned} &P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \Sigma \; (C_L \times V_{CC}{}^2 \times f_o) \; \text{where: } f_i = \text{input frequency in MHz; } C_L = \text{output load capacitance in pF;} \\ &f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V; } \Sigma \; (C_L \times V_{CC}{}^2 \times f_o) = \text{sum of the outputs.} \end{aligned}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVC16245 DL	AC16245 DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVC16245 DGG	AC16245 DGG	SOT362-1
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVCH16245 DL	ACH16245 DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVCH16245 DGG	ACH16245 DGG	SOT362-1

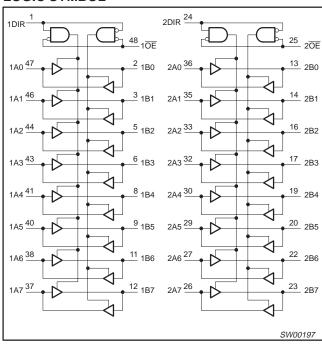
16-bit bus transceiver with direction pin (3-State)

74ALVC16245/ 74ALVCH16245

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	1DIR	Direction control
2, 3, 5, 6, 8, 9, 11, 12	1B0 to 1B7	Data inputs/outputs
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	Vcc	Positive supply voltage
13, 14, 16, 17, 19, 20, 22, 23	2B0 to 2B7	Data inputs/outputs
24	2DIR	Direction control
25	2 OE	Output enable input (active LOW)
36, 35, 33, 32, 30, 29, 27, 26	2A0 to 2A7	Data inputs/outputs
47, 46, 44, 43, 41, 40, 38, 37	1A0 to 1A7	Data inputs/outputs
48	1 OE	Output enable input (active LOW)

LOGIC SYMBOL



FUNCTION TABLE

INP	JTS	INPUTS/	OUTPUT
nOE	nDIR	nAn	nBn
L	L	A = B	inputs
L	Н	inputs	B = A
Н	Х	Z	Z

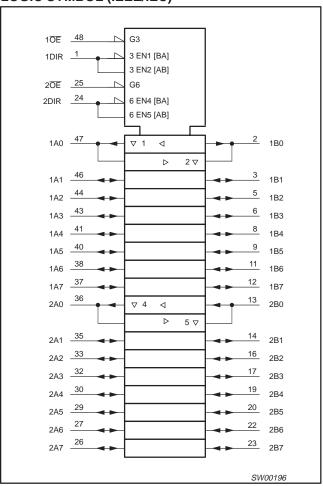
H = HIGH voltage level

L = LOW voltage level

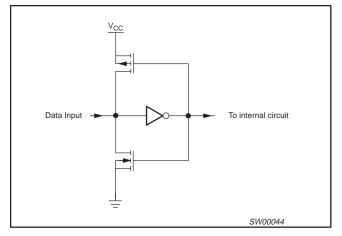
X = don't care

Z = high impedance OFF-state

LOGIC SYMBOL (IEEE/IEC)



BUS HOLD CIRCUIT



16-bit bus transceiver with direction pin (3-State)

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	IITS	UNIT	
STWIBUL	PARAMETER	CONDITIONS	MIN MAX			
	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7		
V _{CC}	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	V	
	DC supply voltage (for low-voltage applications)		1.2	3.6		
VI	DC Input voltage range		0	V _{CC}	V	
Vo	DC output voltage range		0	V _{CC}	V	
T _{amb}	Operating free-air temperature range		-40	+85	°C	
t _r , t _f	Input rise and fall times	V _{CC} = 2.3 to 3.0V V _{CC} = 3.0 to 3.6V	0 0	20 10	ns/V	

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
		For data inputs with bus hold ¹	-0.5 to V _{CC} +0.5	
V_{I}	DC input voltage	For data inputs without bus hold ¹	-0.5 to +4.6	V
		For control pins ¹	-0.5 to +4.6	
l _{OK}	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	±50	mA
Vo	DC output voltage	Note 1	–0.5 to V _{CC} +0.5	V
Io	DC output source or sink current	$V_{O} = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		± 100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package -plastic medium-shrink (SSOP) -plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTE:

^{1.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

16-bit bus transceiver with direction pin (3-State)

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DC CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp	= -40°C to +8	35°C	TINU
			MIN	TYP ¹	MAX	1
W	LUCI Llaval lagus valtaga	V _{CC} = 2.3 to 2.7V	1.7	1.2		V
V_{IH}	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0	1.5		1 '
\/	LOW/level langut valtage	V _{CC} = 2.3 to 2.7V		1.2	0.7	V
V_{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6V		1.5	0.8	1
		$V_{CC} = 2.3 \text{ to } 3.6 \text{V}; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu\text{A}$	V _{CC} -0.2	V _{CC}		
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -6$ mA	V _{CC} -0.3	V _{CC} -0.08		1
\/	HIGH level output voltage	$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12\text{mA}$	V _{CC} -0.6	V _{CC} -0.26		1 _v
V_{OH}	nigh level output voltage	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12\text{mA}$	V _{CC} -0.5	V _{CC} -0.14		7
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12\text{mA}$	V _{CC} -0.6	V _{CC} -0.09		1
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -24\text{mA}$	V _{CC} -1.0	V _{CC} -0.28		1
		$V_{CC} = 2.3 \text{ to } 3.6 \text{V}; \ V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu\text{A}$		GND	0.20	
		$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 6mA$		0.07	0.40	1
V_{OL}	LOW level output voltage	$V_{CC} = 2.3V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12mA$		0.15	0.70	V
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12\text{mA}$		0.14	0.40	1
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 24\text{mA}$		0.27	0.55	1
I _I	Input leakage current	V_{CC} = 2.3 to 3.6V; $V_I = V_{CC}$ or GND		0.1	5	μА
I _{OZ}	3-State output OFF-state current	V_{CC} = 2.3 to 3.6V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND		0.1	10	μА
Icc	Quiescent supply current	$V_{CC} = 2.3 \text{ to } 3.6 \text{V}; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		0.2	40	μА
Δl _{CC}	Additional quiescent supply current given per data I/O pin with bus hold	$V_{CC} = 2.3V$ to 3.6V; $V_I = V_{CC} - 0.6V$; $I_O = 0$		150	750	μА
1 2	Pue hold I OW sustaining surrent	$V_{CC} = 2.3V; V_I = 0.7V$	45	-		
I _{BHL} ²	Bus hold LOW sustaining current	V _{CC} = 3.0V; V _I = 0.8V	75	150		μΑ
12	Bus hold HIGH sustaining current	V _{CC} = 2.3V; V _I = 1.7V	-45			μА
I _{BHH} ²	Bus floid filefi sustaining current	$V_{CC} = 3.0V; V_I = 2.0V$	- 75	-175] μΑ
I _{BHLO} ²	Bus hold LOW overdrive current	V _{CC} = 3.6V	500			μА
I _{BHHO} ²	Bus hold HIGH overdrive current	V _{CC} = 3.6V	-500			μА

- All typical values are at T_{amb} = 25°C.
 Valid for data inputs of bus hold parts.

AC CHARACTERISTICS FOR $V_{CC} = 2.3V$ TO 2.7V RANGE

 $GND = 0V; \ t_{\Gamma} = t_f \leq 2.0ns; \ C_L = 30pF$

SYMBOL	PARAMETER	WAVEFORM	V	UNIT			
			MIN	TYP ¹	MAX		
t _{PHL} /t _{PLH}	Propagation delay nAn to nBn; nBn to nAn	1, 3	1.0	2.0	3.7	ns	
t _{PZH} /t _{PZL}	3-State output enable time nOE to nAn; nOE to nBn	2, 3	1.0	2.7	5.7	ns	
t _{PHZ} /t _{PLZ}	3-State output disable time nOE to nAn; nOE to nBn	2, 3	1.0	2.2	5.2	ns	

NOTES:

^{1.} All typical values are measured at T_{amb} = 25°C and V_{CC} = 2.5V.

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AC CHARACTERISTICS FOR $V_{CC} = 3.0V$ TO 3.6V RANGE AND $V_{CC} = 2.7V$

GND = 0V; $t_r = t_f \le 2.5 \text{ns}$; $C_L = 50 \text{pF}$

			LIMITS								
SYMBOL PARAMETER		WAVEFORM	Vc	$_{\text{C}}$ = 3.3 \pm 0	.3V	١	UNIT				
			MIN	TYP ^{1, 2}	MAX	MIN	TYP ¹	MAX			
t _{PHL} /t _{PLH}	Propagation delay nAn to nBn; nBn to nAn	1, 3	1.0	1.9	3.0	1.0	2.1	3.6	ns		
t _{PZH} /t _{PZL}	3-State output enable time nOE to nAn; nOE to nBn	2, 3	1.0	2.3	4.4	1.0	3.0	5.4	ns		
t _{PHZ} /t _{PLZ}	3-State output disable time nOE to nAn; nOE to nBn	2, 3	1.0	2.8	4.1	1.0	3.1	4.6	ns		

NOTES:

- 1. All typical values are measured at $T_{amb} = 25$ °C.
- 2. Typical value is measured at $V_{CC} = 3.3V$

AC WAVEFORMS FOR $V_{CC} = 2.3V$ TO 2.7V AND V_{CC} < 2.3V RANGE

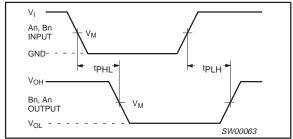
 $V_{M} = 0.5 V_{CC}$ $V_{X} = V_{OL} + 0.15 V_{CC}$

 $V_Y^{\prime}=V_{OH}^{\prime}$ –0.15V V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

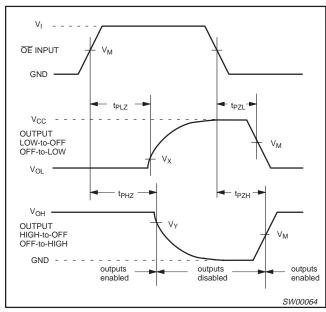
AC WAVEFORMS FOR V_{CC} = 3.0V TO 3.6V AND V_{CC} = 2.7V RANGE

 $V_{M} = 1.5 \text{ V}$ $V_{X} = V_{OL} + 0.3 \text{V}$

 $V_Y = V_{OH} - 0.3V$ V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. $V_1 = 2.7V$



Waveform 1. Input (nAn, nBn) to output (nBn, nAn) propagation delay times

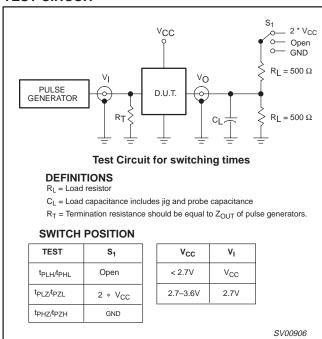


Waveform 2. 3-State enable and disable times

16-bit bus transceiver with direction pin (3-State)

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TEST CIRCUIT



Waveform 3. Load circuitry for switching times

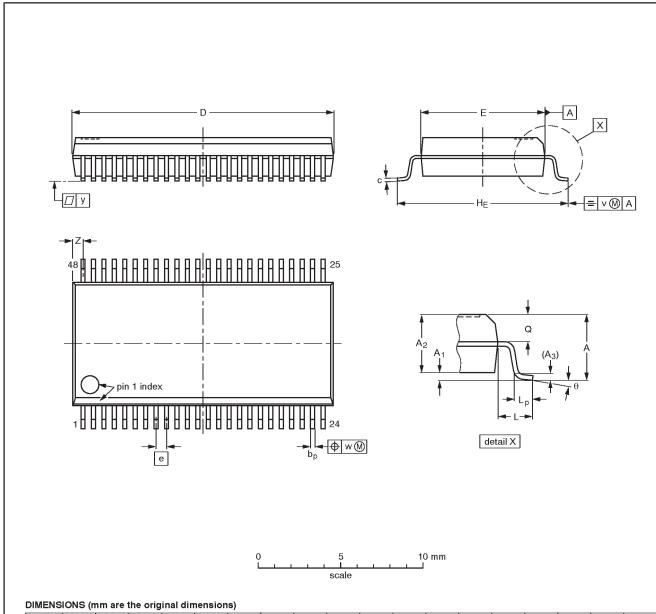
1998 Jun 29 7

2.5V/3.3V 16-bit bus transceiver with direction pin (3-State)

74ALVC16245/ 74ALVCH16245

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

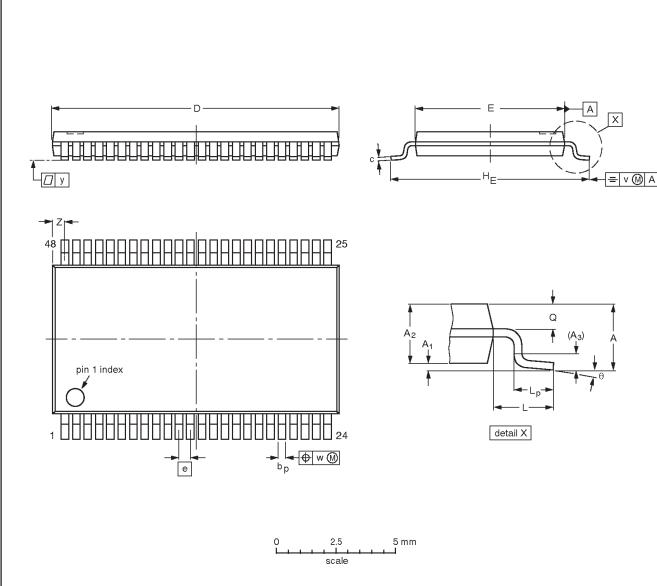
VERS	OUTLINE		REFER	EUROPEAN	ISSUE DATE	
	VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
	SOT370-1		MO-118AA			93-11-02 95-02-04

2.5V/3.3V 16-bit bus transceiver with direction pin (3-State)

74ALVC16245/ 74ALVCH16245

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



DIMENSIONS (mm are the original dimensions).

UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT362-1		MO-153ED				-93-02-03 95-02-10

2.5V/3.3V 16-bit bus transceiver with direction pin (3-State)

74ALVC16245/ 74ALVCH16245

DEFINITIONS						
Data Sheet Identification	Product Status	Definition				
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.				
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